TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

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HIGH CURRENT SWITCHING APPLICATIONS

Low Collector Saturation Voltage
 : V_{CE(sat)} = −0.4 V (Max.) at I_C = −3 A

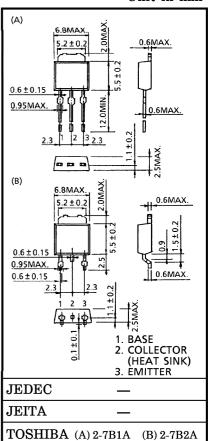
• High Speed Switching Time : $t_{stg} = 1.0 \ \mu s$ (Typ.)

• Complementary to 2SC3074

MAXIMUM RATINGS ($Tc = 25^{\circ}C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Collector-Base Voltage	v_{CBO}	-60	V	
Collector-Emitter Voltage	v_{CEO}	-50	V	
Emitter-Base Voltage	v_{EBO}	-5	V	
Collector Current	IC	- 5	Α	
Base Current	$I_{\mathbf{B}}$	-1	Α	
Collector Power $Ta = 25^{\circ}C$	Da	1.0	w	
Dissipation $Tc = 25^{\circ}C$	$_{ m PC}$	20] "	
Junction Temperature	T_{j}	150	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C	

Unit in mm

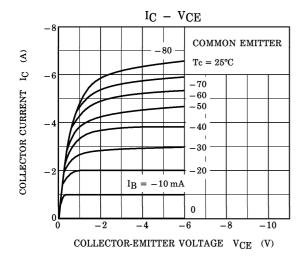


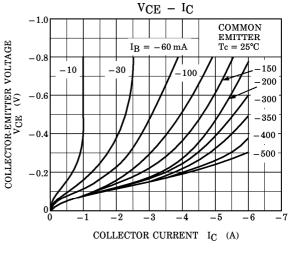
Weight: 0.36 g (Typ.)

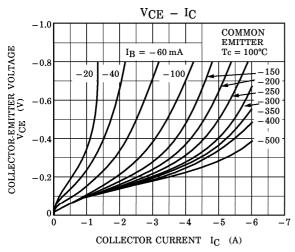
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

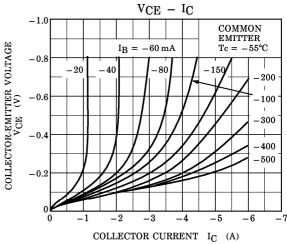
CHARA	ACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cu	t-off Current	I_{CBO}	$V_{CB} = -50 \text{ V}, I_{E} = 0$	_	_	-1	μ A
Emitter Cut	-off Current	$I_{ m EBO}$	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-1	μ A
Collector-En Breakdown		V _(BR) CEO	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$	-50	_	_	V
DC Current Gain		hFE (1) (Note)	$V_{CE} = -1 V, I_{C} = -1 A$	70	_	240	
		hFE (2)	$V_{CE} = -1 V, I_{C} = -3 A$	30		_	
Saturation	${\bf Collector\text{-}Emitter}$	V _{CE} (sat)	$I_C = -3 A, I_B = -0.15 A$	_	-0.2	-0.4	\mathbf{v}
Voltage	Base-Emitter	V _{BE (sat)}	$I_C = -3 \text{ A}, I_B = -0.15 \text{ A}$	_	-0.9	-1.2	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Transition Frequency		${ m f_T}$	$V_{CE} = -4 V, I_{C} = -1 A$	_	60	_	MHz
Collector Output Capacitance		C_{ob}	$egin{aligned} { m V}_{ m CB} = -10 { m V}, \ { m I}_{ m E} = 0, \ { m f} = 1 { m MHz} \end{aligned}$	_	170	_	pF
Switching Time	Turn-on Time	t _{on}	$\begin{array}{c c} & & & & & \\ & 20 \ \mu_{\rm S} & & & & \\ & & 1_{\rm B2} & & & \\ & & 1_{\rm B1} & & & \\ \end{array}$	_	0.1	_	
	Storage Time	$t_{ m stg}$		_	1.0	_	μ s
	Fall Time	t_f	$ \begin{array}{c} -I_{B1} = I_{B2} = 0.15 \text{ A} \\ \text{DUTY CYCLE} \leq 1\% \end{array} \text{V}_{CC} = -30 \text{ V} $	_	0.1	_	

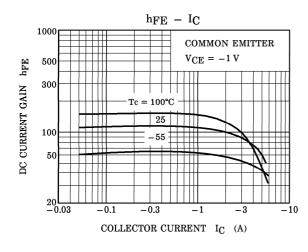
(Note) : hFE (1) Classification O : 70~140 Y : 120~240

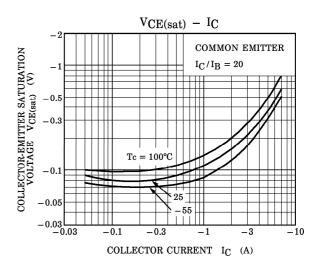


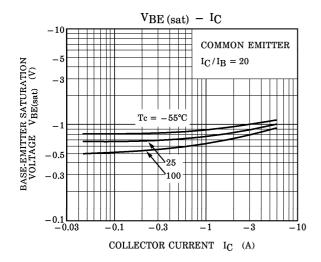


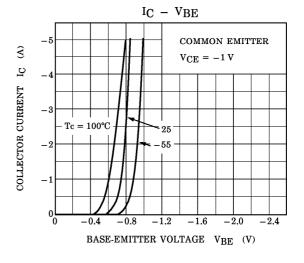


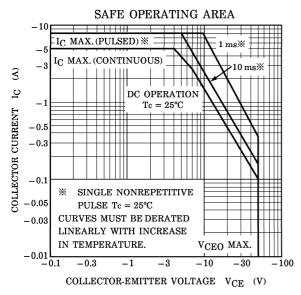


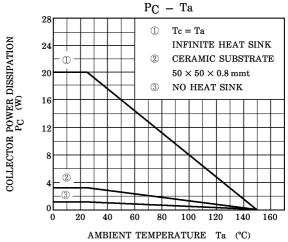












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